

Welcome to [E-XFL.COM](#)

### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I <sup>2</sup> C, IrDA, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I <sup>2</sup> S, POR, PWM, WDT
Number of I/O	37
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	6K x 8
RAM Size	20K x 8
Voltage - Supply (Vcc/Vdd)	1.65V ~ 3.6V
Data Converters	A/D 13x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	49-UFBGA, WLCSP
Supplier Device Package	49-WLCSP (3.29x3.26)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l071cby6tr">https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l071cby6tr</a>

# Contents

<b>1</b>	<b>Introduction</b>	<b>9</b>
<b>2</b>	<b>Description</b>	<b>10</b>
2.1	Device overview	11
2.2	Ultra-low-power device continuum	13
<b>3</b>	<b>Functional overview</b>	<b>14</b>
3.1	Low-power modes	14
3.2	Interconnect matrix	18
3.3	ARM® Cortex®-M0+ core with MPU	19
3.4	Reset and supply management	20
3.4.1	Power supply schemes	20
3.4.2	Power supply supervisor	20
3.4.3	Voltage regulator	21
3.5	Clock management	21
3.6	Low-power real-time clock and backup registers	24
3.7	General-purpose inputs/outputs (GPIOs)	24
3.8	Memories	25
3.9	Boot modes	25
3.10	Direct memory access (DMA)	26
3.11	Analog-to-digital converter (ADC)	26
3.12	Temperature sensor	26
3.12.1	Internal voltage reference (V <sub>REFINT</sub> )	27
3.13	Ultra-low-power comparators and reference voltage	27
3.14	Timers and watchdogs	28
3.14.1	General-purpose timers (TIM2, TIM3, TIM21 and TIM22)	28
3.14.2	Low-power Timer (LPTIM)	29
3.14.3	Basic timer (TIM6, TIM7)	29
3.14.4	SysTick timer	29
3.14.5	Independent watchdog (IWDG)	29
3.14.6	Window watchdog (WWDG)	29
3.15	Communication interfaces	30

## List of figures

Figure 1.	STM32L071xx block diagram	12
Figure 2.	Clock tree	23
Figure 3.	STM32L071xx LQFP100 pinout - 14 x 14 mm	33
Figure 4.	STM32L071xx UFBGA100 ballout - 7 x 7 mm	34
Figure 5.	STM32L071xx LQFP64 pinout - 10 x 10 mm	34
Figure 6.	STM32L071xx TFBGA64 ballout - 5 x 5 mm	35
Figure 7.	STM32L071xx WLCSP49 ballout	36
Figure 8.	STM32L071xx LQFP48 pinout - 7 x 7 mm	37
Figure 9.	STM32L071xx LQFP32 pinout	37
Figure 10.	STM32L071xx UFQFPN32 pinout	38
Figure 11.	Memory map	52
Figure 12.	Pin loading conditions	53
Figure 13.	Pin input voltage	53
Figure 14.	Power supply scheme	54
Figure 15.	Current consumption measurement scheme	54
Figure 16.	IDD vs VDD, at TA= 25/55/85/105 °C, Run mode, code running from Flash memory, Range 2, HSE, 1WS	63
Figure 17.	IDD vs VDD, at TA= 25/55/85/105 °C, Run mode, code running from Flash memory, Range 2, HSI16, 1WS	63
Figure 18.	IDD vs VDD, at TA= 25 °C, Low-power run mode, code running from RAM, Range 3, MSI (Range 0) at 64 KHz, 0 WS	67
Figure 19.	IDD vs VDD, at TA= 25/55/ 85/105/125 °C, Stop mode with RTC enabled and running on LSE Low drive	68
Figure 20.	IDD vs VDD, at TA= 25/55/85/105/125 °C, Stop mode with RTC disabled, all clocks off	69
Figure 21.	High-speed external clock source AC timing diagram	75
Figure 22.	Low-speed external clock source AC timing diagram	76
Figure 23.	HSE oscillator circuit diagram	77
Figure 24.	Typical application with a 32.768 kHz crystal	78
Figure 25.	HSI16 minimum and maximum value versus temperature	79
Figure 26.	VIH/VIL versus VDD (CMOS I/Os)	89
Figure 27.	VIH/VIL versus VDD (TTL I/Os)	89
Figure 28.	I/O AC characteristics definition	92
Figure 29.	Recommended NRST pin protection	93
Figure 30.	ADC accuracy characteristics	96
Figure 31.	Typical connection diagram using the ADC	97
Figure 32.	Power supply and reference decoupling ( $V_{REF+}$ not connected to $V_{DDA}$ )	97
Figure 33.	Power supply and reference decoupling ( $V_{REF+}$ connected to $V_{DDA}$ )	98
Figure 34.	SPI timing diagram - slave mode and CPHA = 0	104
Figure 35.	SPI timing diagram - slave mode and CPHA = 1 <sup>(1)</sup>	105
Figure 36.	SPI timing diagram - master mode <sup>(1)</sup>	105
Figure 37.	I <sup>2</sup> S slave timing diagram (Philips protocol) <sup>(1)</sup>	107
Figure 38.	I <sup>2</sup> S master timing diagram (Philips protocol) <sup>(1)</sup>	107
Figure 39.	LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat package outline	108
Figure 40.	LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat recommended footprint	110
Figure 41.	LQFP100 marking example (package top view)	110
Figure 42.	UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball	

	grid array package outline . . . . .	111
Figure 43.	UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package recommended footprint . . . . .	112
Figure 44.	LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package outline . . . . .	113
Figure 45.	LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat recommended footprint . . . . .	114
Figure 46.	LQFP64 marking example (package top view) . . . . .	115
Figure 47.	TFBGA64 – 64-ball, 5 x 5 mm, 0.5 mm pitch thin profile fine pitch ball grid array package outline . . . . .	116
Figure 48.	TFBGA64 – 64-ball, 5 x 5 mm, 0.5 mm pitch, thin profile fine pitch ball ,grid array recommended footprint . . . . .	117
Figure 49.	TFBGA64 marking example (package top view) . . . . .	118
Figure 50.	WLCSP49 - 49-pin, 3.294 x 3.258 mm, 0.4 mm pitch wafer level chip scale package outline. . . . .	119
Figure 51.	WLCSP49 - 49-pin, 3.294 x 3.258 mm, 0.4 mm pitch wafer level chip scale recommended footprint. . . . .	120
Figure 52.	WLCSP49 marking example (package top view) . . . . .	121
Figure 53.	LQFP48 - 48-pin, 7 x 7 mm low-profile quad flat package outline . . . . .	122
Figure 54.	LQFP48 - 48-pin, 7 x 7 mm low-profile quad flat recommended footprint . . . . .	124
Figure 55.	LQFP48 marking example (package top view) . . . . .	124
Figure 56.	LQFP32 - 32-pin, 7 x 7 mm low-profile quad flat package outline . . . . .	125
Figure 57.	LQFP32 - 32-pin, 7 x 7 mm low-profile quad flat recommended footprint . . . . .	126
Figure 58.	LQFP32 marking example (package top view) . . . . .	127
Figure 59.	UFQFPN32 - 32-pin, 5x5 mm, 0.5 mm pitch ultra thin fine pitch quad flat package outline. . . . .	128
Figure 60.	UFQFPN32 - 32-pin, 5x5 mm, 0.5 mm pitch ultra thin fine pitch quad flat recommended footprint. . . . .	129
Figure 61.	UFQFPN32 marking example (package top view) . . . . .	130
Figure 62.	Thermal resistance . . . . .	132

internal reference voltage ( $V_{REFINT}$ ) in Stop mode. The device remains in reset mode when  $V_{DD}$  is below a specified threshold,  $V_{POR/PDR}$  or  $V_{BOR}$ , without the need for any external reset circuit.

*Note: The start-up time at power-on is typically 3.3 ms when BOR is active at power-up, the start-up time at power-on can be decreased down to 1 ms typically for devices with BOR inactive at power-up.*

The devices feature an embedded programmable voltage detector (PVD) that monitors the  $V_{DD/VDDA}$  power supply and compares it to the  $V_{PVD}$  threshold. This PVD offers 7 different levels between 1.85 V and 3.05 V, chosen by software, with a step around 200 mV. An interrupt can be generated when  $V_{DD/VDDA}$  drops below the  $V_{PVD}$  threshold and/or when  $V_{DD/VDDA}$  is higher than the  $V_{PVD}$  threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

### 3.4.3 Voltage regulator

The regulator has three operation modes: main (MR), low power (LPR) and power down.

- MR is used in Run mode (nominal regulation)
- LPR is used in the Low-power run, Low-power sleep and Stop modes
- Power down is used in Standby mode. The regulator output is high impedance, the kernel circuitry is powered down, inducing zero consumption but the contents of the registers and RAM are lost except for the standby circuitry (wake-up logic, IWDG, RTC, LSI, LSE crystal 32 KHz oscillator, RCC\_CSR).

## 3.5 Clock management

The clock controller distributes the clocks coming from different oscillators to the core and the peripherals. It also manages clock gating for low-power modes and ensures clock robustness. It features:

- **Clock prescaler**  
To get the best trade-off between speed and current consumption, the clock frequency to the CPU and peripherals can be adjusted by a programmable prescaler.
- **Safe clock switching**  
Clock sources can be changed safely on the fly in Run mode through a configuration register.
- **Clock management**  
To reduce power consumption, the clock controller can stop the clock to the core, individual peripherals or memory.
- **System clock source**  
Three different clock sources can be used to drive the master clock SYSCLK:
  - 1-25 MHz high-speed external crystal (HSE), that can supply a PLL
  - 16 MHz high-speed internal RC oscillator (HSI), trimmable by software, that can supply a PLLMultispeed internal RC oscillator (MSI), trimmable by software, able to generate 7 frequencies (65 kHz, 131 kHz, 262 kHz, 524 kHz, 1.05 MHz, 2.1 MHz, 4.2 MHz). When a 32.768 kHz clock source is available in the system (LSE), the MSI frequency can be trimmed by software down to a  $\pm 0.5\%$  accuracy.
- **Auxiliary clock source**  
Two ultra-low-power clock sources that can be used to drive the real-time clock:

### 3.10 Direct memory access (DMA)

The flexible 7-channel, general-purpose DMA is able to manage memory-to-memory, peripheral-to-memory and memory-to-peripheral transfers. The DMA controller supports circular buffer management, avoiding the generation of interrupts when the controller reaches the end of the buffer.

Each channel is connected to dedicated hardware DMA requests, with software trigger support for each channel. Configuration is done by software and transfer sizes between source and destination are independent.

The DMA can be used with the main peripherals: SPI, I<sup>2</sup>C, USART, LPUART, general-purpose timers, and ADC.

### 3.11 Analog-to-digital converter (ADC)

A native 12-bit, extended to 16-bit through hardware oversampling, analog-to-digital converter is embedded into STM32L071xx device. It has up to 16 external channels and 3 internal channels (temperature sensor, voltage reference). Three channels, PA0, PA4 and PA5, are fast channels, while the others are standard channels.

The ADC performs conversions in single-shot or scan mode. In scan mode, automatic conversion is performed on a selected group of analog inputs.

The ADC frequency is independent from the CPU frequency, allowing maximum sampling rate of 1.14 MSPS even with a low CPU speed. The ADC consumption is low at all frequencies (~25  $\mu$ A at 10 kSPS, ~240  $\mu$ A at 1MSPS). An auto-shutdown function guarantees that the ADC is powered off except during the active conversion phase.

The ADC can be served by the DMA controller. It can operate from a supply voltage down to 1.65 V.

The ADC features a hardware oversampler up to 256 samples, this improves the resolution to 16 bits (see AN2668).

An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all scanned channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

The events generated by the general-purpose timers (TIMx) can be internally connected to the ADC start triggers, to allow the application to synchronize A/D conversions and timers.

### 3.12 Temperature sensor

The temperature sensor ( $T_{SENSE}$ ) generates a voltage  $V_{SENSE}$  that varies linearly with temperature.

The temperature sensor is internally connected to the ADC\_IN18 input channel which is used to convert the sensor output voltage into a digital value.

The sensor provides good linearity but it has to be calibrated to obtain good overall accuracy of the temperature measurement. As the offset of the temperature sensor varies from chip to chip due to process variation, the uncalibrated internal temperature sensor is suitable for applications that detect temperature changes only.

To improve the accuracy of the temperature sensor measurement, each device is individually factory-calibrated by ST. The temperature sensor factory calibration data are stored by ST in the system memory area, accessible in read-only mode.

**Table 7. Temperature sensor calibration values**

Calibration value name	Description	Memory address
TSENSE_CAL1	TS ADC raw data acquired at temperature of 30 °C, $V_{DDA} = 3\text{ V}$	0x1FF8 007A - 0x1FF8 007B
TSENSE_CAL2	TS ADC raw data acquired at temperature of 130 °C $V_{DDA} = 3\text{ V}$	0x1FF8 007E - 0x1FF8 007F

### 3.12.1 Internal voltage reference ( $V_{REFINT}$ )

The internal voltage reference ( $V_{REFINT}$ ) provides a stable (bandgap) voltage output for the ADC and Comparators.  $V_{REFINT}$  is internally connected to the ADC\_IN17 input channel. It enables accurate monitoring of the  $V_{DD}$  value (when no external voltage,  $V_{REF+}$ , is available for ADC). The precise voltage of  $V_{REFINT}$  is individually measured for each part by ST during production test and stored in the system memory area. It is accessible in read-only mode.

**Table 8. Internal voltage reference measured values**

Calibration value name	Description	Memory address
VREFINT_CAL	Raw data acquired at temperature of 25 °C $V_{DDA} = 3\text{ V}$	0x1FF8 0078 - 0x1FF8 0079

### 3.13 Ultra-low-power comparators and reference voltage

The STM32L071xx embed two comparators sharing the same current bias and reference voltage. The reference voltage can be internal or external (coming from an I/O).

- One comparator with ultra low consumption
- One comparator with rail-to-rail inputs, fast or slow mode.
- The threshold can be one of the following:
  - External I/O pins
  - Internal reference voltage ( $V_{REFINT}$ )
  - submultiple of Internal reference voltage (1/4, 1/2, 3/4) for the rail to rail comparator.

Both comparators can wake up the devices from Stop mode, and be combined into a window comparator.

The internal reference voltage is available externally via a low-power / low-current output buffer (driving current capability of 1  $\mu\text{A}$  typical).

### 3.14.2 Low-power Timer (LPTIM)

The low-power timer has an independent clock and is running also in Stop mode if it is clocked by LSE, LSI or an external clock. It is able to wakeup the devices from Stop mode.

This low-power timer supports the following features:

- 16-bit up counter with 16-bit autoreload register
- 16-bit compare register
- Configurable output: pulse, PWM
- Continuous / one shot mode
- Selectable software / hardware input trigger
- Selectable clock source
  - Internal clock source: LSE, LSI, HSI or APB clock
  - External clock source over LPTIM input (working even with no internal clock source running, used by the Pulse Counter Application)
- Programmable digital glitch filter
- Encoder mode

### 3.14.3 Basic timer (TIM6, TIM7)

These timers can be used as a generic 16-bit timebase.

### 3.14.4 SysTick timer

This timer is dedicated to the OS, but could also be used as a standard downcounter. It is based on a 24-bit downcounter with autoreload capability and a programmable clock source. It features a maskable system interrupt generation when the counter reaches '0'.

### 3.14.5 Independent watchdog (IWDG)

The independent watchdog is based on a 12-bit downcounter and 8-bit prescaler. It is clocked from an independent 37 kHz internal RC and, as it operates independently of the main clock, it can operate in Stop and Standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free-running timer for application timeout management. It is hardware- or software-configurable through the option bytes. The counter can be frozen in debug mode.

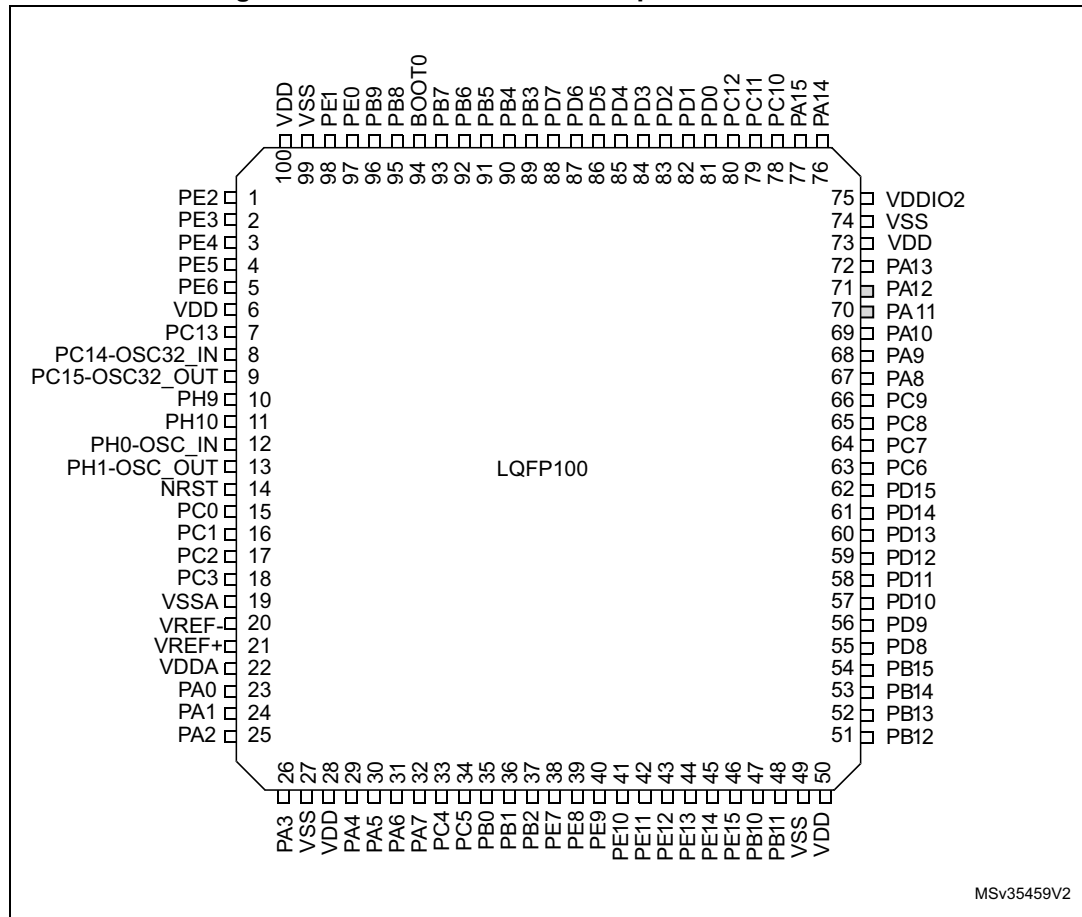
### 3.14.6 Window watchdog (WWDG)

The window watchdog is based on a 7-bit downcounter that can be set as free-running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early warning interrupt capability and the counter can be frozen in debug mode.



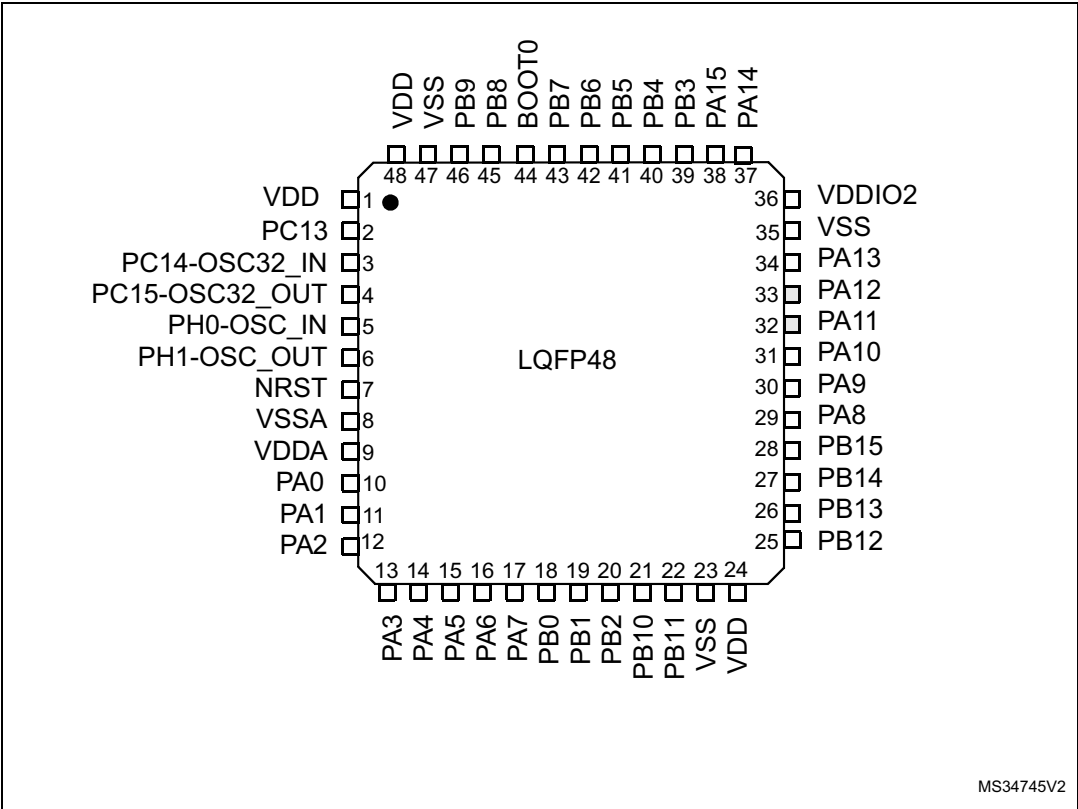
## 4 Pin descriptions

Figure 3. STM32L071xx LQFP100 pinout - 14 x 14 mm



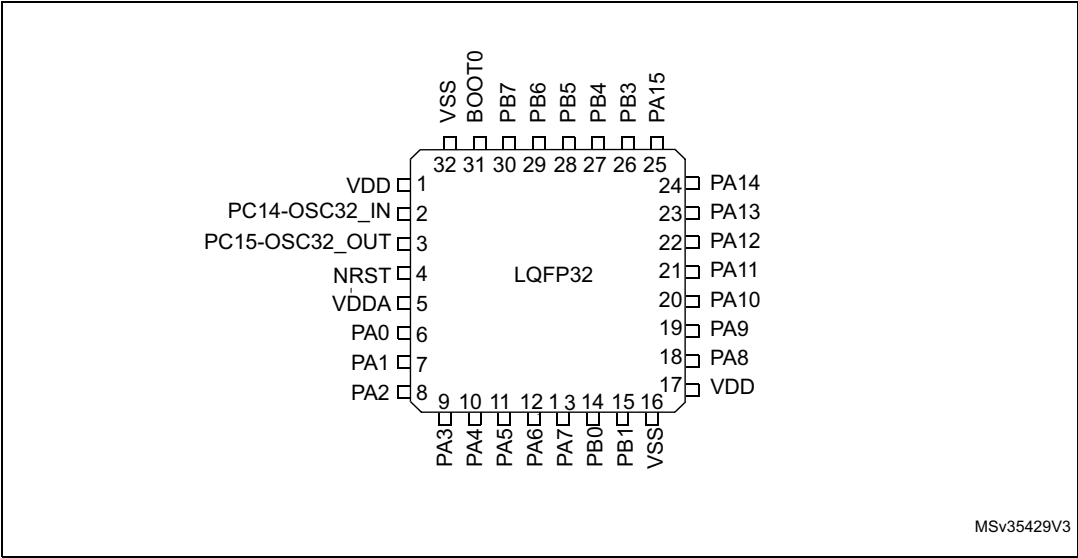
1. The above figure shows the package top view.
2. I/O supplied by VDDIO2.

Figure 8. STM32L071xx LQFP48 pinout - 7 x 7 mm



1. The above figure shows the package top view.
2. I/O supplied by VDDIO2.

Figure 9. STM32L071xx LQFP32 pinout



1. The above figure shows the package top view.

Table 15. STM32L071xxx pin definition (continued)

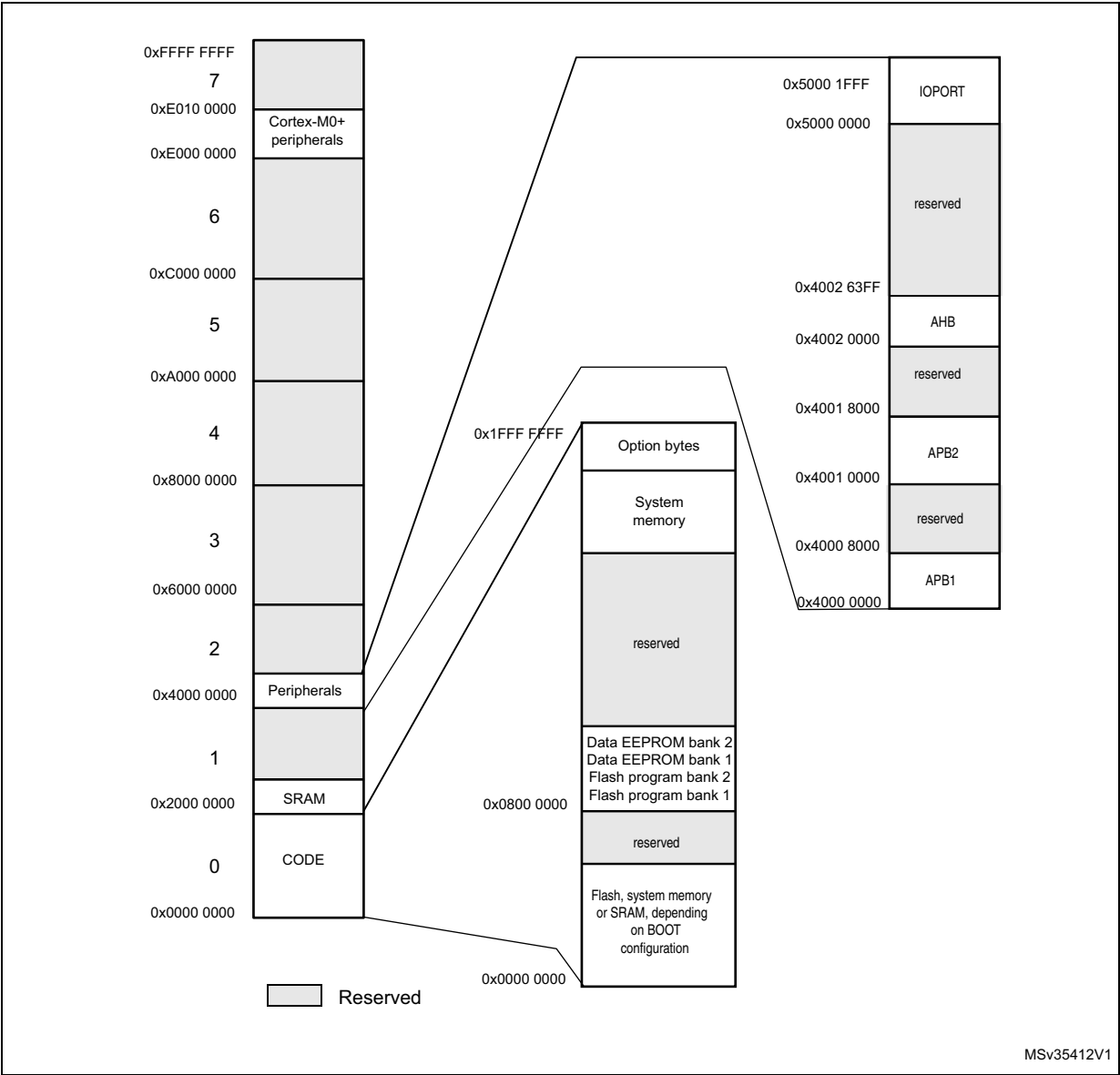
Pin number								Pin name (function after reset)	Pin type	I/O structure	Note	Alternate functions	Additional functions
LQFP32	UFQFPN32 <sup>(1)</sup>	LQFP48	LQFP64	UFBGA64	WLCSP49	LQFP100	UFBG100						
-	-	21	29	G7	G3	47	L10	PB10	I/O	FT	-	TIM2_CH3, LPUART1_TX, SPI2_SCK, I2C2_SCL, LPUART1_RX	-
-	-	22	30	H7	F3	48	L11	PB11	I/O	FT	-	EVENTOUT, TIM2_CH4, LPUART1_RX, I2C2_SDA, LPUART1_TX	-
16	16	23	31	D6	D4	49	F12	VSS	S		-	-	-
17	17	24	32	E6	G2	50	G12	VDD	S		-	-	-
-	-	25	33	H8	G1	51	L12	PB12	I/O	FT	-	SPI2_NSS/I2S2_WS, LPUART1_RTS_DE, I2C2_SMBA, EVENTOUT	-
-	-	26	34	G8	F2	52	K12	PB13	I/O	FTf	-	SPI2_SCK/I2S2_CK, MCO, LPUART1_CTS, I2C2_SCL, TIM21_CH1	-
-	-	27	35	F8	F1	53	K11	PB14	I/O	FTf	-	SPI2_MISO/I2S2_MCK, RTC_OUT, LPUART1_RTS_DE, I2C2_SDA, TIM21_CH2	-
-	-	28	36	F7	E1	54	K10	PB15	I/O	FT	-	SPI2_MOSI/I2S2_SD, RTC_REFIN	-
-	-	-	-	-	-	55	K9	PD8	I/O	FT	-	LPUART1_TX	-
-	-	-	-	-	-	56	K8	PD9	I/O	FT	-	LPUART1_RX	-
-	-	-	-	-	-	57	J12	PD10	I/O	FT	-		-
-	-	-	-	-	-	58	J11	PD11	I/O	FT	-	LPUART1_CTS	-
-	-	-	-	-	-	59	J10	PD12	I/O	FT	-	LPUART1_RTS_DE	-
-	-	-	-	-	-	60	H12	PD13	I/O	FT	-		-
-	-	-	-	-	-	61	H11	PD14	I/O	FT	-		-
-	-	-	-	-	-	62	H10	PD15	I/O	FT	-		-
-	-	-	37	F6	-	63	E12	PC6	I/O	FT	-	TIM22_CH1, TIM3_CH1	-
-	-	-	38	E7	-	64	E11	PC7	I/O	FT	-	TIM22_CH2, TIM3_CH2	-

Table 15. STM32L071xxx pin definition (continued)

Pin number								Pin name (function after reset)	Pin type	I/O structure	Note	Alternate functions	Additional functions
LQFP32	UFQFPN32 <sup>(1)</sup>	LQFP48	LQFP64	UFBGA64	WLCSP49	LQFP100	UFBG100						
-	-	-	-	-	-	81	C9	PD0	I/O	FT	-	TIM21_CH1, SPI2_NSS/I2S2_WS	-
-	-	-	-	-	-	82	B9	PD1	I/O	FT	-	SPI2_SCK/I2S2_CK	-
-	-	-	54	B5	-	83	C8	PD2	I/O	FT	-	LPUART1_RTS_DE, TIM3_ETR, USART5_RX	-
-	-	-	-	-	-	84	B8	PD3	I/O	FT	-	USART2_CTS, SPI2_MISO/I2S2_MCK	-
-	-	-	-	-	-	85	B7	PD4	I/O	FT	-	USART2_RTS_DE, SPI2_MOSI/I2S2_SD	-
-	-	-	-	-	-	86	A6	PD5	I/O	FT	-	USART2_TX	-
-	-	-	-	-	-	87	B6	PD6	I/O	FT	-	USART2_RX	-
-	-	-	-	-	-	88	A5	PD7	I/O	FT	-	USART2_CK, TIM21_CH2	-
26	-	39	55	A5	A3	89	A8	PB3	I/O	FT	-	SPI1_SCK, TIM2_CH2, EVENTOUT, USART1_RTS_DE, USART5_TX	COMP2_INM
27	26	40	56	A4	B3	90	A7	PB4	I/O	FT <sup>f</sup>	-	SPI1_MISO, TIM3_CH1, TIM22_CH1, USART1_CTS, USART5_RX, I2C3_SDA	COMP2_INP
28	27	41	57	C4	A4	91	C5	PB5	I/O	FT	-	SPI1_MOSI, LPTIM1_IN1, I2C1_SMBA, TIM3_CH2/TIM22_CH2, USART1_CK, USART5_CK/USART5_ RTS_DE	COMP2_INP
29	28	42	58	D3	B4	92	B5	PB6	I/O	FT <sup>f</sup>	-	USART1_TX, I2C1_SCL, LPTIM1_ETR,	COMP2_INP

5 Memory mapping

Figure 11. Memory map



1. Refer to the STM32L071xx reference manual for details on the Flash memory organization for each memory size.

## 6.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in [Table 22: Voltage characteristics](#), [Table 23: Current characteristics](#), and [Table 24: Thermal characteristics](#) may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

**Table 22. Voltage characteristics**

Symbol	Definition	Min	Max	Unit
$V_{DD}-V_{SS}$	External main supply voltage (including $V_{DDA}$ , $V_{DDIO2}$ , $V_{DD}$ ) <sup>(1)</sup>	-0.3	4.0	V
$V_{IN}^{(2)}$	Input voltage on FT and FTf pins	$V_{SS} - 0.3$	$V_{DD} + 4.0$	
	Input voltage on TC pins	$V_{SS} - 0.3$	4.0	
	Input voltage on BOOT0	$V_{SS}$	$V_{DD} + 4.0$	
	Input voltage on any other pin	$V_{SS} - 0.3$	4.0	
$ \Delta V_{DD} $	Variations between different $V_{DDx}$ power pins	-	50	mV
$ V_{DDA}-V_{DDx} $	Variations between any $V_{DDx}$ and $V_{DDA}$ power pins <sup>(3)</sup>	-	300	
$ \Delta V_{SS} $	Variations between all different ground pins including $V_{REF-}$ pin	-	50	
$V_{REF+}-V_{DDA}$	Allowed voltage difference for $V_{REF+} > V_{DDA}$	-	0.4	V
$V_{ESD(HBM)}$	Electrostatic discharge voltage (human body model)	see <a href="#">Section 6.3.11</a>		

1. All main power ( $V_{DD}$ ,  $V_{DDA}$ ) and ground ( $V_{SS}$ ,  $V_{SSA}$ ) pins must always be connected to the external power supply, in the permitted range.
2.  $V_{IN}$  maximum must always be respected. Refer to [Table 23](#) for maximum allowed injected current values.
3. It is recommended to power  $V_{DD}$  and  $V_{DDA}$  from the same source. A maximum difference of 300 mV between  $V_{DD}$  and  $V_{DDA}$  can be tolerated during power-up and device operation.  $V_{DDIO2}$  is independent from  $V_{DD}$  and  $V_{DDA}$ : its value does not need to respect this rule.

Table 25. General operating conditions (continued)

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>A</sub>	Temperature range	Maximum power dissipation (range 6)	−40	85	°C
		Maximum power dissipation (range 7)	−40	105	
		Maximum power dissipation (range 3)	−40	125	
T <sub>J</sub>	Junction temperature range (range 6)	$-40\text{ °C} \leq T_A \leq 85\text{ °}$	−40	105	
	Junction temperature range (range 7)	$-40\text{ °C} \leq T_A \leq 105\text{ °C}$	−40	125	
	Junction temperature range (range 3)	$-40\text{ °C} \leq T_A \leq 125\text{ °C}$	−40	130	

1. It is recommended to power V<sub>DD</sub> and V<sub>DDA</sub> from the same source. A maximum difference of 300 mV between V<sub>DD</sub> and V<sub>DDA</sub> can be tolerated during power-up and normal operation.
2. To sustain a voltage higher than V<sub>DD</sub>+0.3V, the internal pull-up/pull-down resistors must be disabled.
3. If T<sub>A</sub> is lower, higher P<sub>D</sub> values are allowed as long as T<sub>J</sub> does not exceed T<sub>J</sub> max (see [Table 24: Thermal characteristics on page 56](#)).

Table 26. Embedded reset and power control block characteristics (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{PVD6}$	PVD threshold 6	Falling edge	2.97	3.05	3.09	V
		Rising edge	3.08	3.15	3.20	
$V_{hyst}$	Hysteresis voltage	BOR0 threshold	-	40	-	mV
		All BOR and PVD thresholds excepting BOR0	-	100	-	

1. Guaranteed by characterization results.

2. Valid for device version without BOR at power up. Please see option "D" in Ordering information scheme for more details.

### 6.3.3 Embedded internal reference voltage

The parameters given in [Table 28](#) are based on characterization results, unless otherwise specified.

Table 27. Embedded internal reference voltage calibration values

Calibration value name	Description	Memory address
VREFINT_CAL	Raw data acquired at temperature of 25 °C $V_{DDA} = 3\text{ V}$	0x1FF8 0078 - 0x1FF8 0079

Table 28. Embedded internal reference voltage<sup>(1)</sup>

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{REFINT\ out}^{(2)}$	Internal reference voltage	$-40\text{ °C} < T_J < +125\text{ °C}$	1.202	1.224	1.242	V
$T_{VREFINT}$	Internal reference startup time	-	-	2	3	ms
$V_{VREF\_MEAS}$	$V_{DDA}$ and $V_{REF+}$ voltage during $V_{REFINT}$ factory measure	-	2.99	3	3.01	V
$A_{VREF\_MEAS}$	Accuracy of factory-measured $V_{REFINT}$ value <sup>(3)</sup>	Including uncertainties due to ADC and $V_{DDA}/V_{REF+}$ values	-	-	±5	mV
$T_{Coeff}^{(4)}$	Temperature coefficient	$-40\text{ °C} < T_J < +125\text{ °C}$	-	25	100	ppm/°C
$A_{Coeff}^{(4)}$	Long-term stability	1000 hours, $T = 25\text{ °C}$	-	-	1000	ppm
$V_{DDCcoeff}^{(4)}$	Voltage coefficient	$3.0\text{ V} < V_{DDA} < 3.6\text{ V}$	-	-	2000	ppm/V
$T_{S\_vrefint}^{(4)(5)}$	ADC sampling time when reading the internal reference voltage	-	5	10	-	µs
$T_{ADC\_BUF}^{(4)}$	Startup time of reference voltage buffer for ADC	-	-	-	10	µs
$I_{BUF\_ADC}^{(4)}$	Consumption of reference voltage buffer for ADC	-	-	13.5	25	µA
$I_{VREF\_OUT}^{(4)}$	VREF_OUT output current <sup>(6)</sup>	-	-	-	1	µA
$C_{VREF\_OUT}^{(4)}$	VREF_OUT output load	-	-	-	50	pF



**Table 40. Peripheral current consumption in Stop and Standby mode<sup>(1)</sup>**

Symbol	Peripheral	Typical consumption, T <sub>A</sub> = 25 °C		Unit
		V <sub>DD</sub> =1.8 V	V <sub>DD</sub> =3.0 V	
I <sub>DD</sub> (PVD / BOR)	-	0.7	1.2	μA
I <sub>REFINT</sub>	-	-	1.7	
-	LSE Low drive <sup>(2)</sup>	0.11	0,13	
-	LSI	0.27	0.31	
-	IWDG	0.2	0.3	
-	LPTIM1, Input 100 Hz	0.01	0,01	
-	LPTIM1, Input 1 MHz	11	12	
-	LPUART1	-	0,5	
-	RTC	0.16	0,3	

1. LPTIM, LPUART peripherals can operate in Stop mode but not in Standby mode.

2. LSE Low drive consumption is the difference between an external clock on OSC32\_IN and a quartz between OSC32\_IN and OSC32\_OUT.-

### 6.3.5 Wakeup time from low-power mode

The wakeup times given in the following table are measured with the MSI or HSI16 RC oscillator. The clock source used to wake up the device depends on the current operating mode:

- Sleep mode: the clock source is the clock that was set before entering Sleep mode
- Stop mode: the clock source is either the MSI oscillator in the range configured before entering Stop mode, the HSI16 or HSI16/4.
- Standby mode: the clock source is the MSI oscillator running at 2.1 MHz

All timings are derived from tests performed under ambient temperature and V<sub>DD</sub> supply voltage conditions summarized in [Table 25](#).

**Table 41. Low-power mode wakeup timings**

Symbol	Parameter	Conditions	Typ	Max	Unit
t <sub>WUSLEEP</sub>	Wakeup from Sleep mode	f <sub>HCLK</sub> = 32 MHz	7	8	Number of clock cycles
t <sub>WUSLEEP_LP</sub>	Wakeup from Low-power sleep mode, f <sub>HCLK</sub> = 262 kHz	f <sub>HCLK</sub> = 262 kHz Flash memory enabled	7	8	
		f <sub>HCLK</sub> = 262 kHz Flash memory switched OFF	9	10	

### Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling 2 LEDs through I/O ports), the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs:

- **Electrostatic discharge (ESD)** (positive and negative) is applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- **FTB**: A Burst of Fast Transient voltage (positive and negative) is applied to  $V_{DD}$  and  $V_{SS}$  through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in [Table 53](#). They are based on the EMS levels and classes defined in application note AN1709.

**Table 53. EMS characteristics**

Symbol	Parameter	Conditions	Level/Class
$V_{FESD}$	Voltage limits to be applied on any I/O pin to induce a functional disturbance	$V_{DD} = 3.3\text{ V}$ , LQFP100, $T_A = +25\text{ °C}$ , $f_{HCLK} = 32\text{ MHz}$ conforms to IEC 61000-4-2	3B
$V_{EFTB}$	Fast transient voltage burst limits to be applied through 100 pF on $V_{DD}$ and $V_{SS}$ pins to induce a functional disturbance	$V_{DD} = 3.3\text{ V}$ , LQFP100, $T_A = +25\text{ °C}$ , $f_{HCLK} = 32\text{ MHz}$ conforms to IEC 61000-4-4	4A

### Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

#### Software recommendations

The software flowchart must include the management of runaway conditions such as:

- Corrupted program counter
- Unexpected reset
- Critical data corruption (control registers...)

#### Prequalification trials

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the oscillator pins for 1 second.

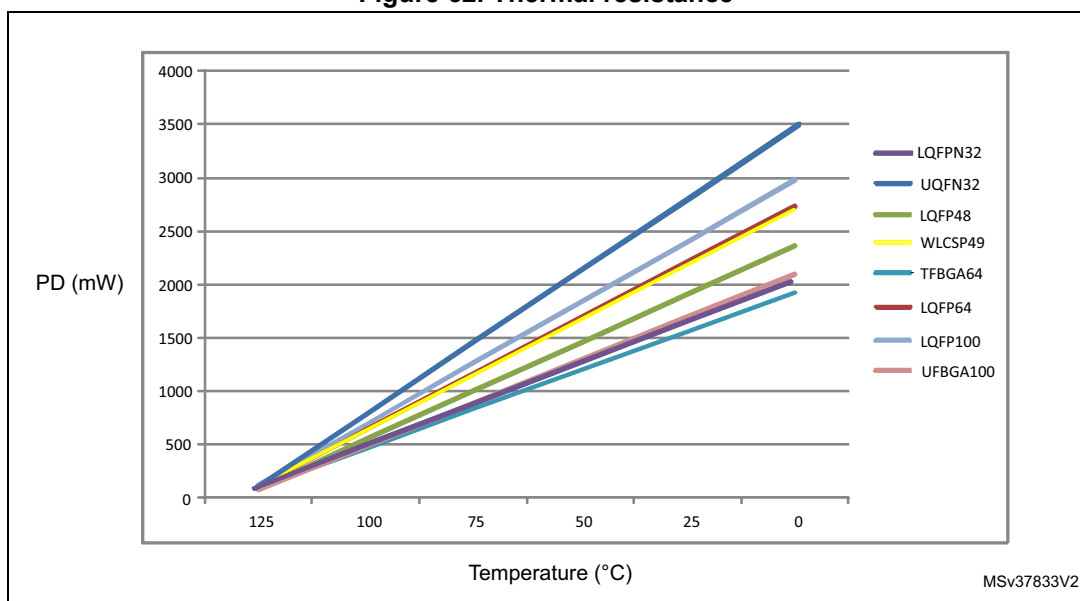
To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

**Table 76. LQPF100 - 100-pin, 14 x 14 mm low-profile quad flat package  
mechanical data**

Symbol	millimeters			inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	15.800	16.000	16.200	0.6220	0.6299	0.6378
D1	13.800	14.000	14.200	0.5433	0.5512	0.5591
D3	-	12.000	-	-	0.4724	-
E	15.800	16.000	16.200	0.6220	0.6299	0.6378
E1	13.800	14.000	14.200	0.5433	0.5512	0.5591
E3	-	12.000	-	-	0.4724	-
e	-	0.500	-	-	0.0197	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0.0°	3.5°	7.0°	0.0°	3.5°	7.0°
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 62. Thermal resistance



### 7.9.1 Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from [www.jedec.org](http://www.jedec.org).

**IMPORTANT NOTICE – PLEASE READ CAREFULLY**

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2016 STMicroelectronics – All rights reserved